# **DISCRETE SEMICONDUCTORS**

# DATA SHEET



# BYD17 series General purpose controlled avalanche rectifiers

Product specification Supersedes data of 1999 Nov 11 2001 Oct 26





# General purpose controlled avalanche rectifiers

### **BYD17 series**

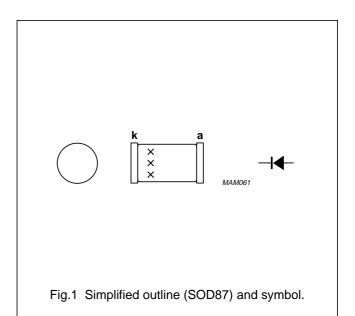
#### **FEATURES**

- · Glass passivated
- High maximum operating temperature
- · Low leakage current
- · Excellent stability
- · Guaranteed avalanche energy absorption capability
- Shipped in 8 mm embossed tape
- Smallest surface mount rectifier outline.

#### **DESCRIPTION**

Cavity free cylindrical glass package through Implotec<sup>™(1)</sup> technology.

This package is hermetically sealed and fatigue free as coefficients of expansion of all used parts are matched.



### **LIMITING VALUES**

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>RRM</sub>	repetitive peak reverse voltage				
	BYD17D		_	200	V
	BYD17G		_	400	V
	BYD17J		_	600	V
	BYD17K		_	800	V
	BYD17M		_	1000	V
V <sub>RWM</sub>	crest working reverse voltage				
	BYD17D		_	200	V
	BYD17G		_	400	V
	BYD17J		_	600	V
	BYD17K		_	800	V
	BYD17M		_	1000	V
V <sub>R</sub>	continuous reverse voltage				
	BYD17D		_	200	V
	BYD17G		_	400	V
	BYD17J		_	600	V
	BYD17K		_	800	V
	BYD17M		_	1000	V

<sup>(1)</sup> Implotec is a trademark of Philips.

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SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
I <sub>F(AV)</sub>	average forward current	T <sub>tp</sub> = 105 °C; averaged over any 20 ms period; see Figs 2 and 4	_	1.5	A
		T <sub>amb</sub> = 65 °C; PCB mounting (see Fig.9); averaged over any 20 ms period; see Figs 3 and 4	-	0.6	A
I <sub>FSM</sub>	non-repetitive peak forward current	t = 10 ms half sinewave; T <sub>j</sub> = T <sub>j max</sub> prior to surge; V <sub>R</sub> = V <sub>RRMmax</sub>	_	20	A
E <sub>RSM</sub>	non-repetitive peak reverse avalanche energy	L = 120 mH; $T_j = T_{j \text{ max}}$ prior to surge; inductive load switched off	_	7	mJ
T <sub>stg</sub>	storage temperature		-65	+175	°C
Tj	junction temperature	see Fig.5	-65	+175	°C

#### **ELECTRICAL CHARACTERISTICS**

T<sub>i</sub> = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V <sub>F</sub>	forward voltage	$I_F = 1 \text{ A}; T_j = T_{j \text{ max}}; \text{see Fig.6}$	_	_	0.93	V
		I <sub>F</sub> = 1 A; see Fig.6	_	_	1.05	V
V <sub>(BR)R</sub>	reverse avalanche breakdown voltage	I <sub>R</sub> = 0.1 mA				
	BYD17D		225	_	_	V
	BYD17G		450	_	_	V
	BYD17J		650	_	_	V
	BYD17K		900	_	_	V
	BYD17M		1100	_	_	V
I <sub>R</sub>	reverse current	V <sub>R</sub> = V <sub>RRMmax</sub> ; see Fig.7	_	_	1	μΑ
		$V_R = V_{RRMmax}$ ; $T_j = 165 ^{\circ}\text{C}$ ; see Fig.7	_	_	100	μΑ
t <sub>rr</sub>	reverse recovery time	when switched from $I_F = 0.5$ A to $I_R = 1$ A; measured at $I_R = 0.25$ A; see Fig.10	_	3	_	μs
C <sub>d</sub>	diode capacitance	V <sub>R</sub> = 0 V; f = 1 MHz; see Fig.8	_	21	_	pF

### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R <sub>th j-tp</sub>	thermal resistance from junction to tie-point		30	K/W
R <sub>th j-a</sub>	thermal resistance from junction to ambient	note 1	150	K/W

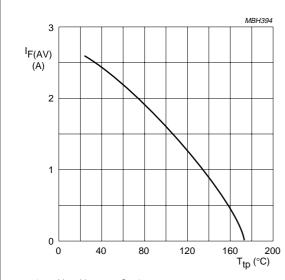
### Note

1. Device mounted on epoxy-glass printed-circuit board, 1.5 mm thick; thickness of copper ≥40 μm, see Fig.9. For more information please refer to the *"General Part of associated Handbook"*.

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#### **GRAPHICAL DATA**



a = 1.57;  $V_R = V_{RRMmax}$ ;  $\delta = 0.5$ .

Fig.2 Maximum permissible average forward current as a function of tie-point temperature (including losses due to reverse leakage).

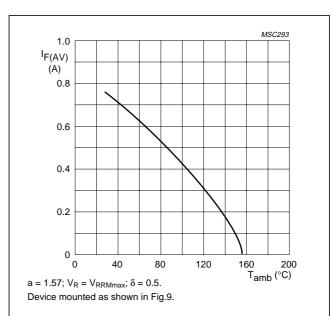
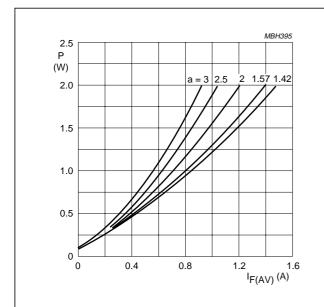


Fig.3 Maximum permissible average forward current as a function of ambient temperature (including losses due to reverse leakage).



 $a = I_{F(RMS)}/I_{F(AV)}; \ V_R = V_{RRMmax}; \ \delta = 0.5.$ 

Fig.4 Maximum steady state power dissipation (forward plus leakage current losses, excluding switching losses) as a function of average forward current.

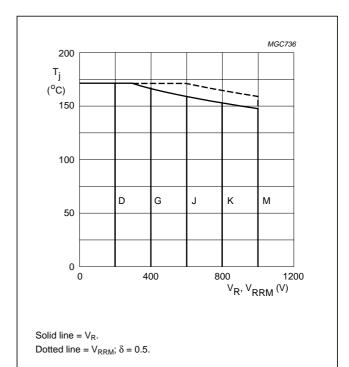
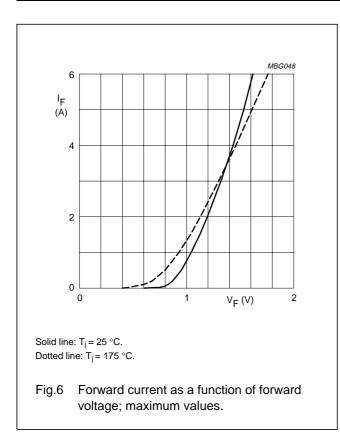
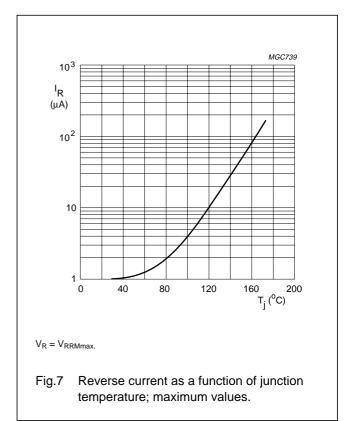


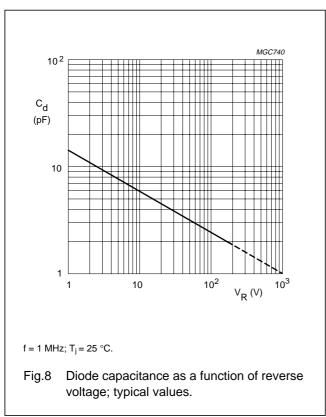
Fig.5 Maximum permissible junction temperature as a function of reverse voltage.

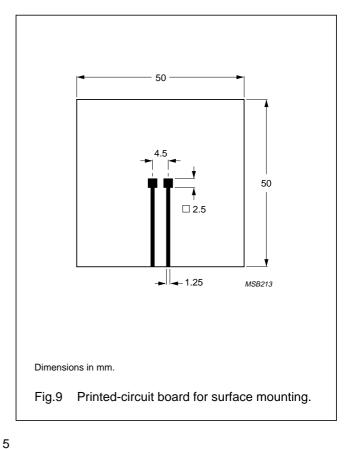
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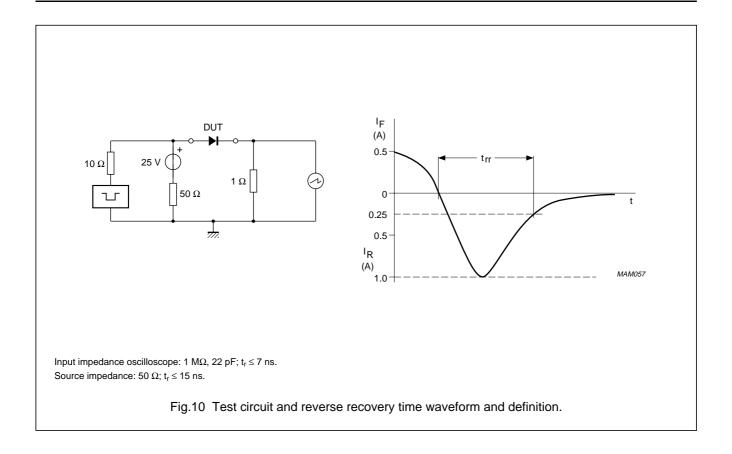




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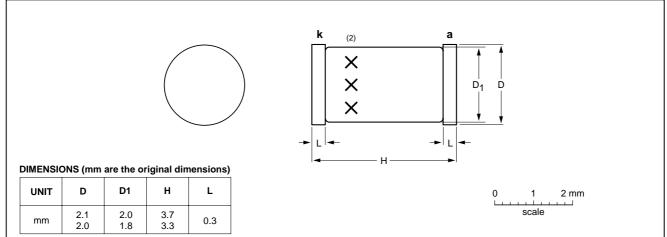
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### **PACKAGE OUTLINE**

Hermetically sealed glass surface mounted package; Implotec $^{\text{TM}(1)}$  technology; 2 connectors

SOD87



#### Notes

- 1. Implotec is a trademark of Philips.
- 2. The marking indicates the cathode.

OUTLINE REFERENCES				EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE
SOD87	100H03					<del>99-03-31</del> 99-06-04

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#### **DATA SHEET STATUS**

DATA SHEET STATUS(1)	PRODUCT STATUS <sup>(2)</sup>	DEFINITIONS
Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
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**NOTES** 

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